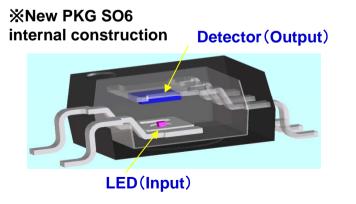


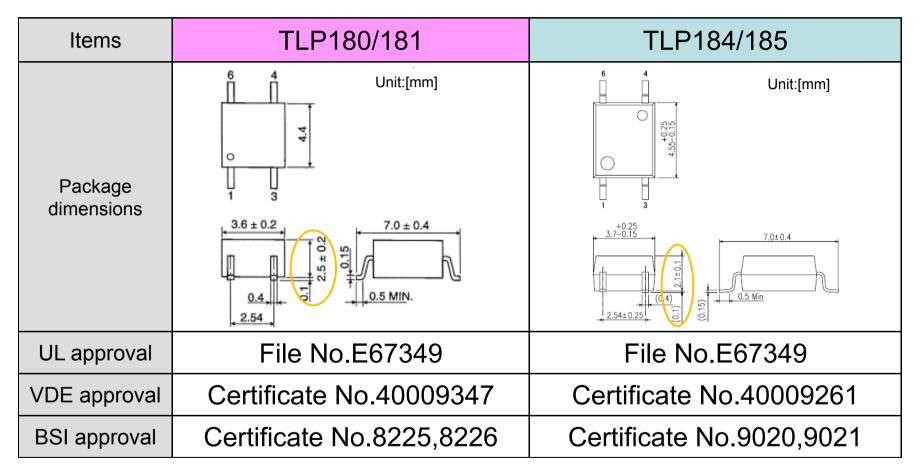
TLP180/181 vs. TLP184/185 TLP280/281/284/285 vs. TLP290/291 comparison chart



Toshiba Discrete Semiconductor Technology Corporation Discrete Semiconductor Technical Marketing & Support Div. Dec. 2011

TLP180/181 vs. TLP184/185

Package dimensions Comparison



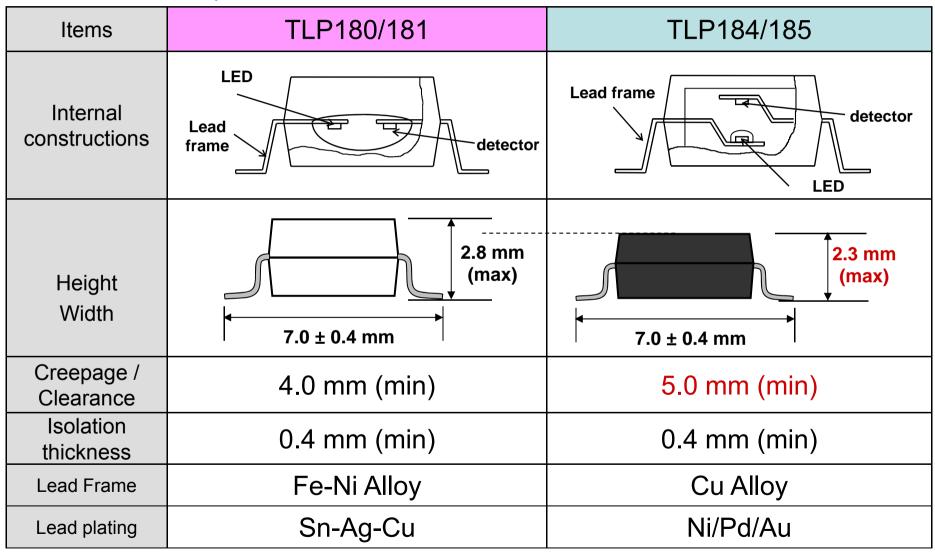
Example rand patterns remain the same.

Reference

TLP180/181 vs. TLP184/185

Reference

Construction Comparison



4

Absolute Maximum Ratings are basically same.

(Ta=25°C)

Characteristics	Symbol	Unit	TLP180	TLP184	TLP181	TLP185
Forward current	IF	mA	±50	±50	50	50
Pulse forward current(Note1)	IFP	А	±1	±1	1	1
Reverse voltage	VR	V	—	-	5	5
Collector-emitter voltage	VCEO	V	80	80	80	80
Emitter-collector voltage	VECO	V	7	7	7	7
Collector current	IC	mA	50	50	50	50
Collector power dissipation	PC	mW	150	150	150	150
Operating temperature range	Topr	°C	-55~110	-55~110	-55~110	-55~110
Storage temperature range	Tstr	°C	-55~125	-55~125	-55~125	-55~125
Lead soldering temperature	Tsol	°C	260(10s)	260(10s)	260(10s)	260(10s)
Total package power dissipation	PT	mW	200	200	200	200
Isolation voltage(Note2)	BVs	Vrms	3750	3750	3750	3750

Note 1: Pulse width \leq 100 µs, frequency = 100Hz

Note 2: AC, 1 min, R.H.≤60% LED pins and detector pins are shorted respectively.

Comparison of Main Characteristics

Reference

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Electrical characteristics (Ta=25°C)

TLP180/184

CHARACTERISTIC	SYMBOL	UNIT	TEST ONDITION		TLP180			TLP184	
CHARACTERISTIC	STIVIDUL	UNIT	TEST ONDITION	Min.	typ.	Max.	Min.	typ.	Max.
Forward Voltage	VF	V	IF=±10mA	1	1.15	1.3	1.1	1.25	1.4
Collector Dark Current	ICEO	uA	VCE=48V	-	0.01	0.1	-	0.01	0.08
Collector-Emitter Breakdown Voltage	V(BR)CEO	V	lc=0.5mA	80	-	-	80	-	-
Emitter-Collector Breakdown Voltage	V(BR)ECO	V	IE=0.1mA	7	I	-	7	I	-
Current Transfer Ratio	IC/IF	%	IF=±5mA,VCE=5V	50	-	600	50	-	400
Saturated CTR	IC/IF(sat)	%	IF=±1mA.VCE=0.4V	-	60	-	-	60	-
Saturated CTR Rank GB	10/11 (Sat)	70	II - ⊥ IIIIA,VCE-0.4V	30	-	-	30		-
Collector-Emitter Saturation Voltage	VCE(sat)	V	IC=2.4mA,IF=±8mA	-	-	0.4	-	-	0.3
Collector-Emitter Saturation Voltage Rank GB	VCE(Sat)	v	IC=0.2mA,IF=±1mA	-	-	0.4	-	-	0.3
OFF-State Collector Current	IC(off)	uA	VF=0.7V,VCE=48V	-	-	10	-	1	10
CTR symmetry	IC(ratio)	uA	lc(IF=-5mA)/lc(IF=5mA)	0.33	-	3	0.33	-	3

TLP181/185

CHARACTERISTIC	SYMBOL	UNIT	IT TEST ONDITION		TLP181			TLP185	
CHARACTERISTIC	STIVIBUL	UNIT	TEST UNDITION	Min.	typ.	Max.	Min.	typ.	Max.
Forward Voltage	VF	V	IF=10mA	1	1.15	1.3	1.1	1.25	1.4
Reverse Current	IR	uA	VR=5V	-	-	10	-	-	5
Collector Dark Current	ICEO	uA	VCE=48V	-	0.01	0.1	-	0.01	0.08
Collector-Emitter Breakdown Voltage	V(BR)CEO	V	lc=0.5mA	80	-	_	80	-	_
Emitter-Collector Breakdown Voltage	V(BR)ECO	V	IE=0.1mA	7	-	-	7	-	-
Current Transfer Ratio	IC/IF	%	IF=5mA,VCE=5V	50	-	600	50	-	400
Saturated CTR				-	60	-	-	60	-
Saturated CTR Rank GB	IC/IF(sat)	%	IF=1mA,VCE=0.4V	30	-	-	30	-	-
Collector-Emitter Saturation Voltage	VCE (a at)	V	IC=2.4mA,IF=8mA	-	-	0.4	-	-	0.3
Collector-Emitter Saturation Voltage Rank GB	VCE(sat)	v	IC=0.2mA,IF=1mA	-	-	0.4	-	-	0.3
OFF-State Collector Current	IC(off)	uA	VF=0.7V,VCE=48V	-	-	10	-	1	10



Comparison of CTR rank

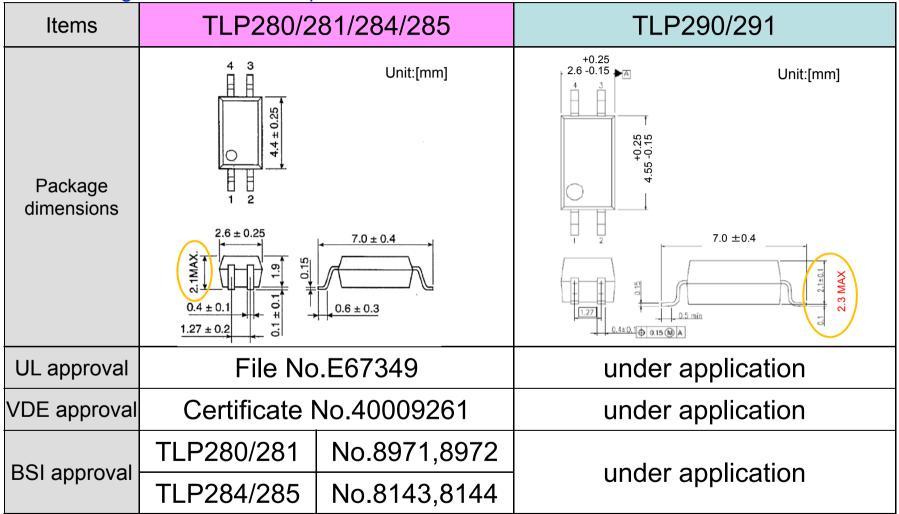
The upper limit of CTR is changed to 400% in TLP184/185 from 600% in TLP180/181.

- (1) If you are using "BL rank" in TLP180/181, please order a "BLL rank" in TLP184/185.
- (2) Please note that the upper limit of Blank and GB rank in TLP184/185 is 400%.

Т	LP180			T	TLP184			
	min	max			min	max		
Blank	50	600		Blank	50	400		
Y rank	50	150		Y rank	50	150		
GR rank	100	300		GR rank	100	300		
BL rank	200	600		BLL rank	200	400		
GB rank	100	600		GB rank	100	400		
Т	LP181]	T	TLP185			
	min	max			min	max		
Blank	50	600		Blank	50	400		
Y rank	50	150		Y rank	50	150		
GR rank	100	300		GR rank	100	300		
GRL rank	100	200		GRL rank	100	200		
GRH rank	150	300		GRH rank	150	300		
BL rank	200	600		-	-	-		
BLL rank	200	400		BLL rank	200	400		
GB rank	100	600		GB rank	100	400		

TLP280/281/284/285 vs. TLP290/291 Reference

Package dimensions Comparison

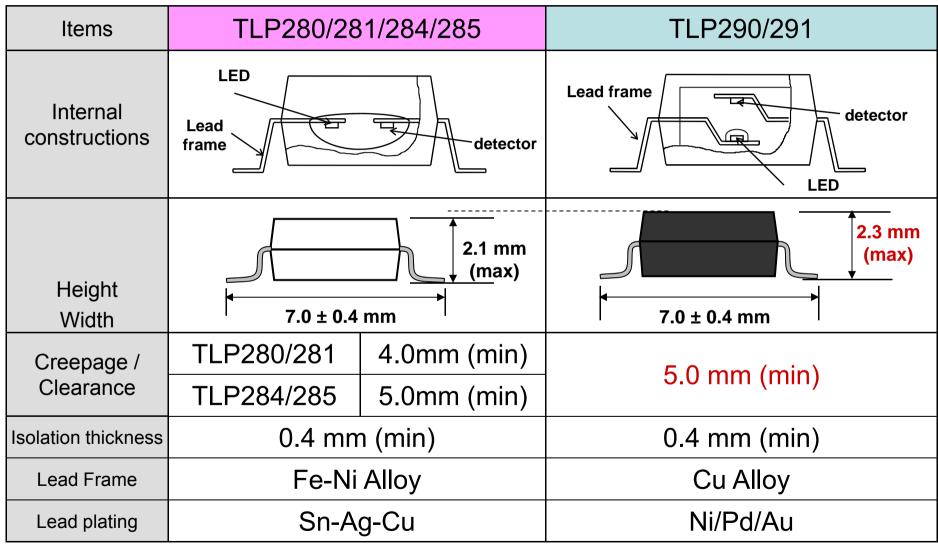


Example rand patterns remain the same.

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TLP280/281/284/285 vs. TLP290/291 Reference

Construction Comparison



9

Absolute Maximum Ratings are basically same.

(Ta=25°C)

	CHARACTERISTIC	Symbol	Unit	TLP280	TLP284	TLP290*	TLP281	TLP285	TLP291*
	Forward current	I _F	mA	±	50	±50	50		50
LED	Pulse forward current (Note1)	I _{FP}	А	±	:1	±1	-	1	1
	Reverse Voltage	V _R	V		_	_		5	5
L	Collector-emitter voltage	V_{CEO}	V	8	0	80	8	0	80
etector	Emitter-collector voltage	V _{ECO}	V	-	7	7	-	7	7
Dete	Collector current	I _C	mA	5	0	50	5	0	50
	Collector power dissipation	Pc	mW	15	50	150	15	50	150
Ope	rating temperature range	Topr	С°	-55~100	-55 ~ 110	-55~110	-55~100	-55~110	-55~110
Stor	age temperature range	Tstg	С°	-55~	~125	-55~125	-55~	~125	-55 ~ 125
Lead	d soldering temperature	Tsol	°C	260(10s)	260(10s)	260(10s)	260(10s)
Tota	I package power dissipation	Ρ _T	mW	20	00	200	20	00	200
Isola	ation voltage(Note2)	BVs	Vrms	2500	3750	3750	2500	3750	3750

* Under development

Note 1: Pulse width \leq 100 µs, frequency = 100Hz

Note 2: AC, 1 min, R.H.≤60% LED pins and detector pins are shorted respectively.

Comparison of Main Characteristics

Electrical characteristics (Ta=25°C)

TLP280 / 284 vs. TLP290

	SYMBOL	UNIT	TEST ONDITION	TL	P280, TLP2	284		TLP290 *	
CHARACTERISTIC	STIVIBUL	UNIT	TEST UNDITION	Min.	typ.	Max.	Min.	typ.	Max.
Forward Voltage	VF	V	IF=±10mA	1	1.15	1.3	1.1	1.25	1.4
Collector Dark Current	ICEO	uA	VCE=48V	-	0.01	0.1	-	0.01	0.08
Collector-Emitter Breakdown Voltage	V(BR)CEO	V	lc=0.5mA	80	-	-	80	-	-
Emitter-Collector Breakdown Voltage	V(BR)ECO	V	IE=0.1mA	7	-	-	7	-	-
Current Transfer Ratio	IC/IF	%	IF=±5mA,VCE=5V	50	-	600	50	-	400
Saturated CTR	IC/IF(sat)	%	IF=±1mA.VCE=0.4V	-	60	-	-	60	-
Saturated CTR Rank GB	10/11 (Sat)	70	II -1 IIIA, VCE-0.4V	30	-	-	30		-
Collector-Emitter Saturation Voltage	VCE(sat)	V	IC=2.4mA,IF=±8mA	-	-	0.4	-	-	0.3
Collector-Emitter Saturation Voltage Rank GB	VCE(Sat)	v	IC=0.2mA,IF=±1mA	-	-	0.4	-	-	0.3
OFF-State Collector Current	IC(off)	uA	VF=0.7V,VCE=48V	-	-	10	-	1	10
CTR symmetry	IC(ratio)	uA	lc(IF=-5mA)/lc(IF=5mA)	0.33	-	3	0.33	-	3

* Under development

TLP281 / 285 vs. TLP291

				TL	TLP281, TLP285			TLP291 *		
CHARACTERISTIC	SYMBOL	UNIT	TEST ONDITION	Min.	typ.	Max.	Min.	TLP291 ³ typ. 1.25 - 0.01 - - 60 - -	Max.	
Forward Voltage	VF	V	IF=10mA	1	1.15	1.3	1.1	1.25	1.4	
Reverse Current	IR	uA	VR=5V	-	-	10	-	-	5	
Collector Dark Current	ICEO	uA	VCE=48V	-	0.01	0.1	-	0.01	0.08	
Collector-Emitter Breakdown Voltage	V(BR)CEO	V	lc=0.5mA	80	-	-	80	-	-	
Emitter-Collector Breakdown Voltage	V(BR)ECO	V	IE=0.1mA	7	-	-	7	-	-	
Current Transfer Ratio	IC/IF	%	IF=5mA,VCE=5V	50	-	600	50	-	400	
Saturated CTR				-	60	-	-	60	-	
Saturated CTR Rank	IC/IF(sat)	%	IF=1mA,VCE=0.4V	30	-	-	30	-	-	
Collector-Emitter Saturation Voltage			IC=2.4mA,IF=8mA	-	-	0.4	-	-	0.3	
Collector-Emitter Saturation Voltage Rank GB	VCE(sat)	V	IC=0.2mA,IF=1mA	-	-	0.4	-	-	0.3	
OFF-State Collector Current	IC(off)	uA	VF=0.7V,VCE=48V	-	-	10	-	1	10	

* Under development



Reference

Comparison of CTR rank

The upper limit of CTR is changed to 400% in TLP290/291 from 600% in TLP280/281/284/285.

- (1) If you are using "BL rank" in TLP280/281/284/285, please order a "BLL rank" in TLP290/291.
- (2) Please note that the upper limit of Blank and GB rank in TLP290/291 is 400%.

TLP	280 / 284			T	TLP290				
	min	max			min	max			
Blank	50	600		Blank	50	400			
Y rank	50	150		Y rank	50	150			
GR rank	100	300		GR rank	100	300			
BL rank	200	600		BLL rank	200	400			
GB rank	100	600		GB rank	100	400			
TLP	281 / 285			TI					
	min	max			min	max			
Blank	50	600		Blank	50	400			
Y rank	50	150]	Y rank	50	150			
GR rank	100	300] [GR rank	100	300			
GRL rank	100	200		GRL rank	100	200			
GRH rank	150	300		GRH rank	150	300			
BL rank	200	600		-					
BLL rank	200	400		BLL rank	200	400			
GB rank	100	600		GB rank	100	400			



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